







Tools &

Software



CSD17579Q5A

SLPS524 - MARCH 2015

CSD17579Q5A 30 V N-Channel NexFET™ Power MOSFETs

1 Features

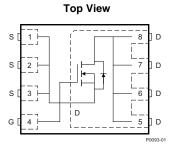
- Low Q_g and Q_{gd}
- Low R_{DS(on)}
- Low Thermal Resistance
- Avalanche Rated
- Pb-Free Terminal Plating
- RoHS Compliant
- Halogen Free
- SON 5 mm × 6 mm Plastic Package

2 Applications

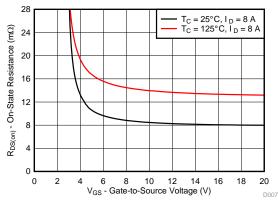
- Point-of-Load Synchronous Buck Converter for Applications in Networking, Telecom, and Computing Systems
- Optimized for Control FET Applications

3 Description

This 30 V, 8.4 m Ω , SON 5 mm x 6mm NexFETTM power MOSFET is designed to minimize losses in power conversion applications.



R_{DS(on)} vs V_{GS}



Product Summary

T _A = 25°	C	TYPICAL VA	UNIT	
V _{DS}	Drain-to-Source Voltage 30			
Qg	Gate Charge Total (4.5 V)	5.4	nC	
Q _{gd}	Gate Charge Gate-to-Drain	1.2	nC	
Р	Drain-to-Source On-Resistance	$V_{GS} = 4.5 V$	11.6	mΩ
R _{DS(on)}	Drain-to-Source On-Resistance	V _{GS} = 10 V 8.4		mΩ
V _{GS(th)}	Threshold Voltage	1.5	V	

Ordering Information⁽¹⁾

5										
Device	Media	Qty	Package	Ship						
CSD17579Q5A	13-Inch Reel	2500 SON 5 x 6 mm		Tape and						
CSD17579Q5AT	7-Inch Reel	250	Plastic Package	Reel						

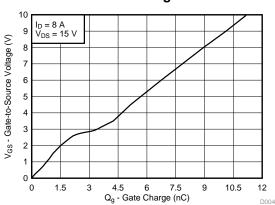
(1) For all available packages, see the orderable addendum at the end of the data sheet.

Absolute Maximum Ratings

T _A = 2	5°C	VALUE	UNIT
V_{DS}	Drain-to-Source Voltage	30	V
V_{GS}	Gate-to-Source Voltage	±20	V
	Continuous Drain Current (Package limited)	25	
ID	Continuous Drain Current (Silicon limited), $T_{C} = 25^{\circ}C$	46	А
	Continuous Drain Current ⁽¹⁾	14	
I _{DM}	Pulsed Drain Current ⁽²⁾	105	А
D	Power Dissipation ⁽¹⁾	3.1	W
PD	Power Dissipation, $T_C = 25^{\circ}C$	36	vv
T _J , T _{stg}	Operating Junction and Storage Temperature Range	-55 to 150	ů
E _{AS}	Avalanche Energy, single pulse $I_D = 17 A, L = 0.1 mH$	14.5	mJ

(1) Typical $R_{\theta JA}$ = 40°C/W on a 1 inch², 2 oz. Cu pad on a 0.06 inch thick FR4 PCB.

(2) Max $R_{\theta JC}$ = 4.3 °C/W, pulse duration ≤100 µs, duty cycle ≤1%



Gate Charge

An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.



Table of Contents

 1
 Features
 1

 2
 Applications
 1

 3
 Description
 1

 4
 Revision History
 2

 5
 Specifications
 3

 5.1
 Electrical Characteristics
 3

 5.2
 Thermal Information
 3

 5.3
 Typical MOSFET Characteristics
 4

 6
 Device and Documentation Support
 7

Trademarks 7 6.1 Electrostatic Discharge Caution......7 6.2 Glossary 7 6.3 Mechanical, Packaging, and Orderable 7 Information 8 Q5A Package Dimensions 8 7.1 7.2 Recommended Stencil Opening 10 7.3 7.4 Q5A Tape and Reel Information 10

4 Revision History

DATE	REVISION	NOTES
March 2015	*	Initial release.

5 Specifications

5.1 Electrical Characteristics

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

	PARAMETER	TEST CONDITIONS	MIN TYP	MAX	UNIT
STATIC	CHARACTERISTICS				
BV_{DSS}	Drain-to-Source Voltage	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	30		V
I _{DSS}	Drain-to-Source Leakage Current	$V_{GS} = 0 V, V_{DS} = 24 V$		1	μA
I _{GSS}	Gate-to-Source Leakage Current	$V_{DS} = 0 V, V_{GS} = 20 V$		100	nA
V _{GS(th)}	Gate-to-Source Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	1.0 1.5	2.0	V
Р	Drain-to-Source On-Resistance	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 8 \text{ A}$	11.6	13.3	mΩ
R _{DS(on)}	Drain-to-Source On-Resistance	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 8 \text{ A}$	8.4	9.7	mΩ
9 _{fs}	Transconductance	$V_{DS} = 3 V, I_{D} = 8 A$	36		S
DYNAMI	C CHARACTERISTICS				
C _{iss}	Input Capacitance		796	1030	pF
C _{oss}	Output Capacitance	$V_{GS} = 0 V, V_{DS} = 15 V, f = 1 MHz$	95	124	pF
C _{rss}	Reverse Transfer Capacitance		40	52	pF
R_{G}	Series Gate Resistance		1.9	3.8	Ω
Qg	Gate Charge Total (4.5 V)		5.4	7	nC
Qg	Gate Charge Total (10 V)		11.6	15.1	nC
Q _{gd}	Gate Charge Gate-to-Drain	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 8 \text{ A}$	1.2		nC
Q _{gs}	Gate Charge Gate-to-Source		2.3		nC
Q _{g(th)}	Gate Charge at V _{th}		1.1		nC
Q _{oss}	Output Charge	$V_{DS} = 15 V, V_{GS} = 0 V$	2.9		nC
t _{d(on)}	Turn On Delay Time		3		ns
t _r	Rise Time	V _{DS} = 15 V, V _{GS} = 10 V,	7		ns
t _{d(off)}	Turn Off Delay Time	$I_{DS} = 8 \text{ A}, \text{ R}_{G} = 0 \Omega$	13		ns
t _f	Fall Time		1		ns
DIODE C	CHARACTERISTICS				
V _{SD}	Diode Forward Voltage	$I_{SD} = 8 \text{ A}, V_{GS} = 0 \text{ V}$	0.8	1.0	V
Q _{rr}	Reverse Recovery Charge	V _{DS} = 15 V, I _F = 8 A,	4.2		nC
t _{rr}	Reverse Recovery Time	di/dt = 300 A/µs	5.7		ns

5.2 Thermal Information

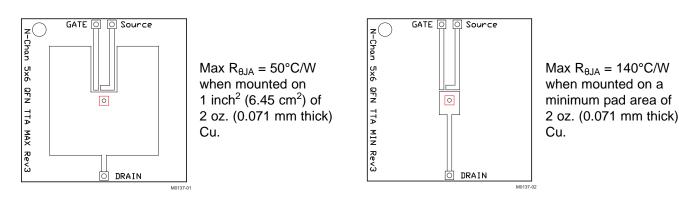
 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

	THERMAL METRIC	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction-to-Case Thermal Resistance ⁽¹⁾			4.3	°C/W
$R_{\theta JA}$	Junction-to-Ambient Thermal Resistance ⁽¹⁾⁽²⁾			50	°C/W

(1) R_{θJC} is determined with the device mounted on a 1 inch² (6.45 cm²), 2 oz. (0.071 mm thick) Cu pad on a 1.5 inches x 1.5 inches (3.81 cm x 3.81 cm), 0.06 inch (1.52 mm) thick FR4 PCB. R_{θJC} is specified by design, whereas R_{θJA} is determined by the user's board design.

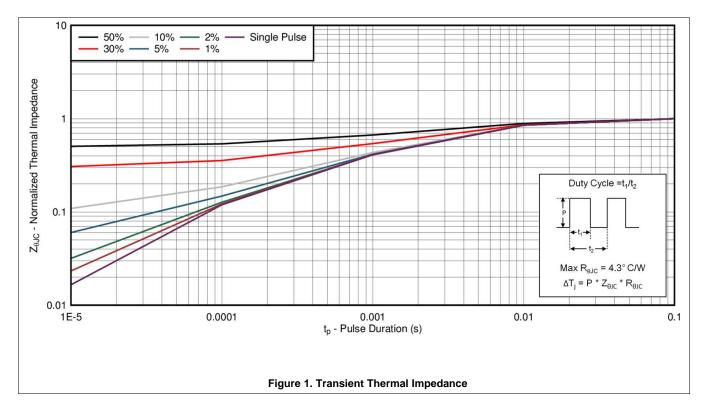
(2) Device mounted on FR4 material with 1 inch² (6.45-cm²), 2 oz. (0.071 mm thick) Cu.





5.3 Typical MOSFET Characteristics

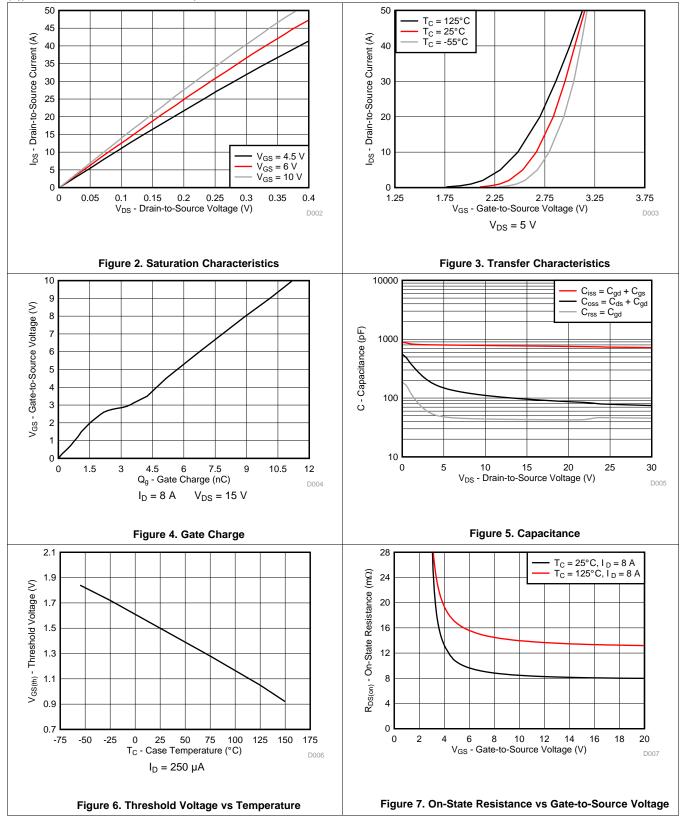
 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$





Typical MOSFET Characteristics (continued)

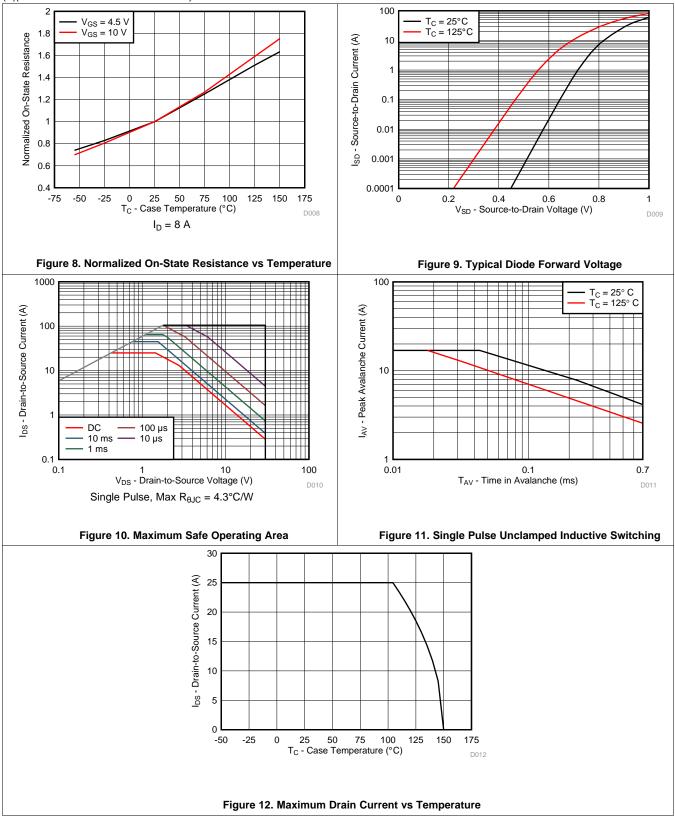
 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$





Typical MOSFET Characteristics (continued)

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$





6 Device and Documentation Support

6.1 Trademarks

NexFET is a trademark of Texas Instruments. All other trademarks are the property of their respective owners.

6.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

6.3 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

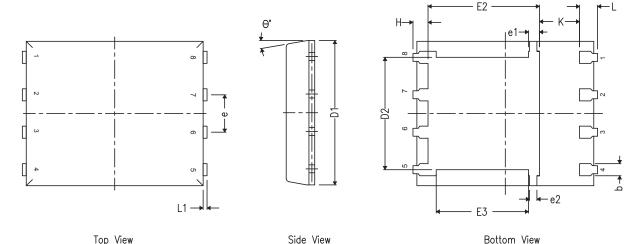
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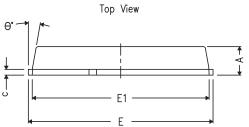
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7 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

7.1 Q5A Package Dimensions







DIM	MILLIMETERS							
DIM	MIN	NOM	MAX					
A	0.90	1.00	1.10					
b	0.33	0.41	0.51					
с	0.20	0.25	0.34					
D1	4.80	4.90	5.00					
D2	3.61	3.81	4.02					
E	5.90	6.00	6.10					
E1	5.70	5.75	5.80					
E2	3.38	3.58	3.78					
E3	3.03	3.13	3.23					
е	1.17	1.27	1.37					
e1	0.27	0.37	0.47					
e2	0.15	0.25	0.35					
Н	0.41	0.56	0.71					
К	1.10							
L	0.51	0.61	0.71					
L1	0.06	0.13	0.20					
θ	0°		12°					

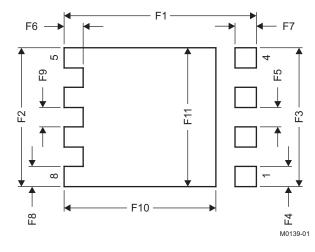
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7.2 Recommended PCB Pattern



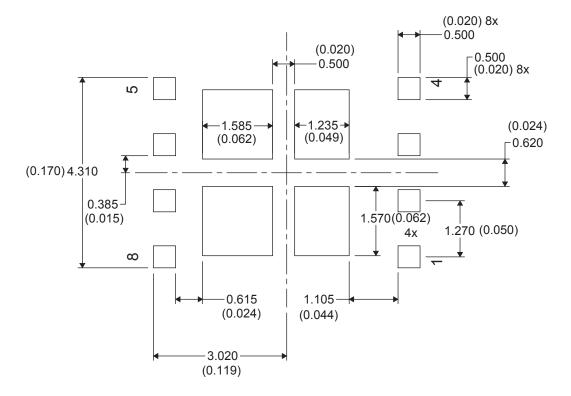
DIM	MILLIM	ETERS	INCHES			
DIVI	MIN	MAX	MIN	MAX		
F1	6.205	6.305	0.244	0.248		
F2	4.46	4.56	0.176	0.18		
F3	4.46	4.56	0.176	0.18		
F4	0.65	0.7	0.026	0.028		
F5	0.62	0.67	0.024	0.026		
F6	0.63	0.68	0.025	0.027		
F7	0.7	0.8	0.028	0.031		
F8	0.65	0.7	0.026	0.028		
F9	0.62	0.67	0.024	0.026		
F10	4.9	5	0.193	0.197		
F11	4.46	4.56	0.176	0.18		

For recommended circuit layout for PCB designs, see application note SLPA005 – Reducing Ringing Through PCB Layout Techniques.

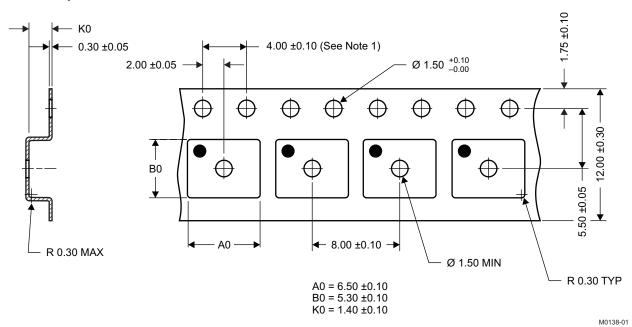
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7.3 Recommended Stencil Opening



7.4 Q5A Tape and Reel Information



Notes:

- 1. 10-sprocket hole-pitch cumulative tolerance ±0.2
- 2. Camber not to exceed 1 mm in 100 mm, noncumulative over 250 mm
- 3. Material: black static-dissipative polystyrene
- 4. All dimensions are in mm (unless otherwise specified)
- 5. A0 and B0 measured on a plane 0.3 mm above the bottom of the pocket



29-Jun-2018

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
CSD17579Q5A	ACTIVE	VSONP	DQJ	8	2500	Pb-Free (RoHS Exempt)	CU SN	Level-1-260C-UNLIM		CSD17579	Samples
CSD17579Q5AT	ACTIVE	VSONP	DQJ	8	250	Pb-Free (RoHS Exempt)	CU SN	Level-1-260C-UNLIM	-55 to 150	CSD17579	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

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